

120 V power Schottky rectifier





Features

- · High junction temperature capability
- Avalanche rated
- · Low leakage current
- Good trade-off between leakage current and forward voltage drop
- ECOPACK[®]2 compliant

Applications

- · Switching diode
- SMPS
- DC/DC converter
- · LED lighting
- Notebook adapter

Description

This single Schottky rectifier is suited for high frequency switch mode power supply.

Packaged in TO-220AC, the STPS20120D is optimized for use in notebook & LCD adaptors, desktop SMPS, providing in these applications a margin between the remaining voltages applied on the diode and the voltage capability of the diode.

Product status link				
STPS20120D				
Product summary				
Symbol Value				
I _{F(AV)}	20 A			
V _{RRM}	120 V			
T _j (max.) 175 °C				
V _F (typ.)	0.72 V			



1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C unless otherwise specified)

Symbol	Parameter	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage	120	V		
I _{F(RMS)}	Forward rms current	Forward rms current 30			
I _{F(AV)}	Average forward current , δ = 0.5 square wave	20	А		
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		200	Α	
P _{ARM}	Repetitive peak avalanche power	619	W		
T _{stg}	Storage temperature range -6			°C	
T _j	Maximum operating junction temperature (1) 175			°C	

^{1.} $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	2.2	°C/W

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Poverse leakage gurrent	T _j = 25 °C	\/ -\/	-		20	μΑ
'R'	Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$	-	3	10	mA
		T _j = 25 °C	I _F = 5 A	-		0.70	
		T _j = 125 °C	IF - 3 A	-	0.54	0.58	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 10 A	-		0.80	V
V _F ⁽²⁾ Forward voltage drop	Polward voltage drop	T _j = 125 °C		-	0.62	0.66	V
		T _j = 25 °C	I _F = 20 A	-		0.93	
		T _j = 125 °C	1F - 20 A	-	0.72	0.76	

^{1.} Pulse test: tp = 5 ms, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

 $P = 0.56 \times I_{F(AV)} + 0.010 \times I_{F}^{2}(RMS)$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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^{2.} Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$



1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current

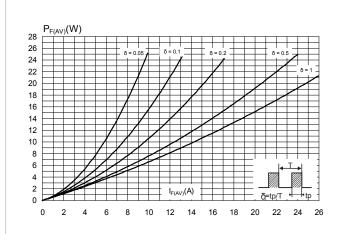


Figure 2. Average forward current versus ambient temperature (δ = 0.5)

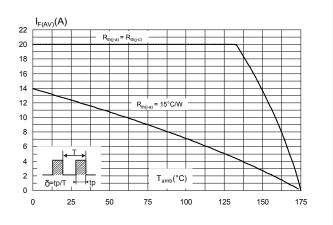


Figure 3. Normalized avalanche power derating versus pulse duration ($T_j = 125\,^{\circ}\text{C}$)

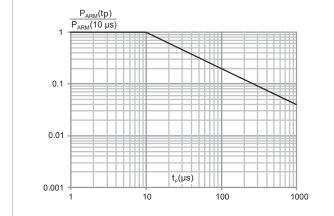
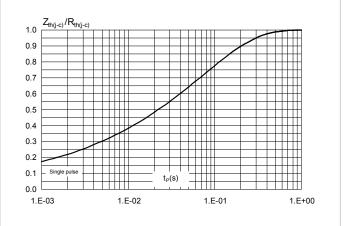


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration



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1.E+02
1.E+01
1.E-02
1.E-03
1.E-04
1.E-05
0 10 20 30 40 50 60 70 80 90 100 110 120

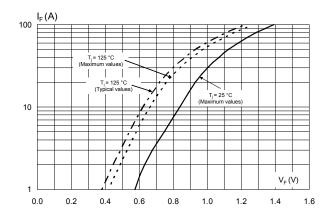
Figure 6. Junction capacitance versus reverse voltage applied (typical values)

1000 C(pF)

1000 V_R(V)

10 1 10 100

Figure 7. Forward voltage drop versus forward current



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2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 TO-220AC package information

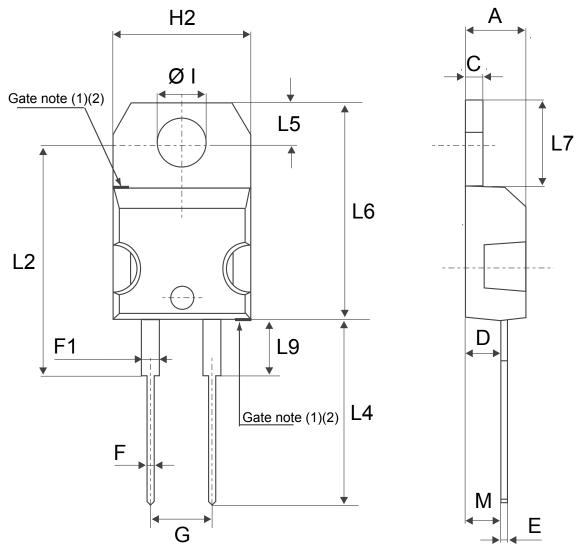
Epoxy meets UL 94,V0

Cooling method: by conduction (C)

Recommended torque value: 0.55 N·m

Maximum torque value: 0.70 N·m

Figure 8. TO-220AC package outline



- (1): Max resin gate protusion 0.5 mm
- (2) :Resin gate position is accepted in each of the two positions shown on the drawings or their symmetrical

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Table 4. TO-220AC package mechanical data

	Dimensions				
Ref.	Millimeters		Inches (for reference only)		
	Min.	Max.	Min.	Max.	
А	4.40	4.60	0.173	0.181	
С	1.23	1.32	0.048	0.051	
D	2.40	2.72	0.094	0.107	
E	0.49	0.70	0.019	0.027	
F	0.61	0.88	0.024	0.034	
F1	1.14	1.70	0.044	0.066	
G	4.95	5.15	0.194	0.202	
H2	10.00	10.40	0.393	0.409	
L2	16.40	0 typ.	0.645 typ.		
L4	13.00	14.00	0.511	0.551	
L5	2.65	2.95	0.104	0.116	
L6	15.25	15.75	0.600	0.620	
L7	6.20	6.60	0.244	0.259	
L9	3.50	3.93	0.137	0.154	
M	2.60	typ.	0.102	typ.	
Diam	3.75	3.85	0.147	0.151	

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3 Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS20120D	STPS20120D	TO-220AC	1.86 g	50	Tube

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Revision history

Table 6. Document revision history

Date	Version	Changes
18-Feb-2005	1	First issue.
02-Jul-2018	2	Removed figure 4 and figure 5. Updated Figure 3. Normalized avalanche power derating versus pulse duration ($T_j = 125~^{\circ}\text{C}$) and Table 1. Absolute ratings (limiting values at 25 $^{\circ}\text{C}$ unless otherwise specified). Minor text changes to improve readability.

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